

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Texas Instruments</u> <u>LMV358Q1MM/NOPB</u>

For any questions, you can email us directly: sales@integrated-circuit.com



Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP















LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

LMV3xx-N/-Q1 Single, Dual, and Quad General Purpose, Low-Voltage, Rail-to-Rail Output Operational Amplifiers

1 Features

- (For V⁺ = 5 V and V⁻ = 0 V, Unless Otherwise Specified)
- LMV321-N, LMV358-N, and LMV324-N are available in Automotive AEC-Q100 Grade 1 and 3 versions
- Ensured 2.7-V and 5-V Performance
- No Crossover Distortion
- Industrial Temperature Range -40°C to +125°C
- · Gain-Bandwidth Product 1 MHz
- Low Supply Current
- LMV321-N 130 μA
- LMV358-N 210 μA
- LMV324-N 410 μA
- Rail-to-Rail Output Swing At 10 kΩ V⁺− 10 mV & V⁻+ 65 mV
- V_{CM} Range -0.2 V to V⁺- 0.8 V

2 Applications

- Active Filters
- General Purpose Low Voltage Applications
- General Purpose Portable Devices

3 Description

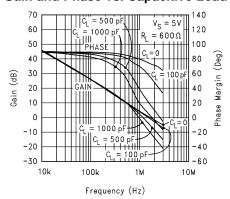
The LMV358-N and LMV324-N are low-voltage (2.7 V to 5.5 V) versions of the dual and quad commodity op amps LM358 and LM324 (5 V to 30 V). The LMV321-N is the single channel version. The LMV321-N, LMV358-N, and LMV324-N are the most cost-effective solutions for applications where low-voltage operation, space efficiency, and low price are important. They offer specifications that meet or exceed the familiar LM358 and LM324. The LMV321-N, LMV358-N, and LMV324-N have rail-to-rail output swing capability and the input common-mode voltage range includes ground. They all exhibit excellent speed to power ratio, achieving 1 MHz of bandwidth and 1-V/µs slew rate with low supply current.

Device Information⁽¹⁾

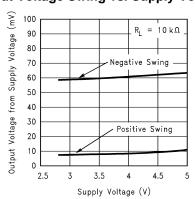
PART NUMBER	PACKAGE	BODY SIZE (NOM)
LMV321-N	SOT-23 (5)	2.90 mm x 1.60 mm
LIVI V 32 I-IN	SC70 (5)	2.00 mm x 1.25 mm
LMV321-N-Q1	SOT-23 (5)	2.90 mm x 1.60 mm
LMV/224 N	SOIC (14)	8.65 mm x 3.91 mm
LMV324-N	TSSOP (14)	5.00 mm x 4.40 mm
LMV324-N-Q1	SOIC (14)	8.65 mm x 3.91 mm
LIVI V 324-IN-Q I	TSSOP (14)	5.00 mm x 4.40 mm
LMV/250 N	SOIC (8)	4.90 mm x 3.91 mm
LMV358-N	VSSOP (8)	3.00 mm x 3.00 mm
110/050 11 04	SOIC (8)	4.90 mm x 3.91 mm
LMV358-N-Q1	VSSOP (8)	3.00 mm x 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Gain and Phase vs. Capacitive Load



Output Voltage Swing vs. Supply Voltage





Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

Table of Contents	Tak	ole	of	Col	nte	nts
-------------------	-----	-----	----	-----	-----	-----

1	Features 1		8.1 Overview	16
2	Applications 1		8.2 Functional Block Diagram	17
3	Description 1		8.3 Feature Description	17
4	Revision History2		8.4 Device Functional Modes	19
5	Description (Continued)	9	Application and Implementation	20
6	Pin Configuration and Functions3		9.1 Application Information	20
7	_		9.2 Typical Applications	20
′	Specifications	10	Power Supply Recommendations	
	7.2 ESD Ratings - Commercial	11	Layout	32
	7.3 ESD Ratings - Automotive		11.1 Layout Guidelines	32
	7.4 Recommended Operating Conditions		11.2 Layout Example	33
	7.5 Thermal Information	12	Device and Documentation Support	34
	7.6 2.7-V DC Electrical Characteristics		12.1 Related Links	
	7.7 2.7-V AC Electrical Characteristics		12.2 Trademarks	34
	7.8 5-V DC Electrical Characteristics		12.3 Electrostatic Discharge Caution	34
	7.9 5-V AC Electrical Characteristics		12.4 Glossary	
	7.10 Typical Characteristics	13	Mechanical, Packaging, and Orderable	
8	Detailed Description 16		Information	34

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision I (February 2013) to Revision J

Page

Changes from Revision H (February 2013) to Revision I

Page

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

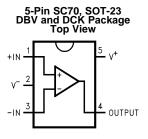
SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

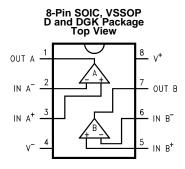
5 Description (Continued)

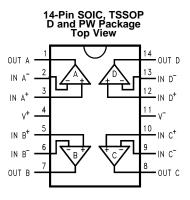
The LMV321-N is available in the space saving 5-Pin SC70, which is approximately half the size of the 5-Pin SOT23. The small package saves space on PC boards and enables the design of small portable electronic devices. It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

The chips are built with Texas Instruments's advanced submicron silicon-gate BiCMOS process. The LMV321-N/LMV358-N/LMV324-N have bipolar input and output stages for improved noise performance and higher output current drive.

6 Pin Configuration and Functions







Pin Functions

	FIII FUNCTIONS					
		PIN				
NAME	LMV321-N DVB, DCK	LMV358-N D, DGK	LMV324-N D, PW	TYPE	DESCRIPTION	
+IN	1	-	-	I	Noninverting input	
IN A+	-	3	3	I	Noninverting input, channel A	
IN B+	-	5	5	I	Noninverting input, channel B	
IN C+	-	-	10	I	Noninverting input, channel C	
IN D+	-	-	12	I	Noninverting input, channel D	
-IN	3	-	-	I	Inverting input	
IN A-	-	2	2	I	Inverting input, channel A	
IN B-	-	6	6	I	Inverting input, channel B	
IN C-	-	-	9	I	Inverting input, channel C	
IN D-	-	-	13	I	Inverting input, channel D	
OUTPUT	4	-	-	0	Output	
OUT A	-	1	1	0	Output, channel A	
OUT B	-	7	7	0	Output, channel B	
OUT C	-	-	8	0	Output , channel C	
OUT D	-	-	14	0	Output, channel D	
V+	5	8	4	Р	Positive (highest) power supply	
V-	2	4	11	Р	Negative (lowest) power supply	

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

7 Specifications

7.1 Absolute Maximum Ratings

See (1)(2).

	MIN	MAX	UNIT
Differential Input Voltage	±Sup	ply Voltage	V
Input Voltage	-0.3	+Supply Voltage	V
Supply Voltage (V ⁺ –V ⁻)		5.5	V
Output Short Circuit to V +	(3)		
Output Short Circuit to V -	(4)		
Soldering Information: Infrared or Convection (30 sec)		260	°C
Junction Temperature (5)		150	°C
Storage temperature T _{stg}	- 65	150	°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Recommended Operating Conditions indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office / Distributors for availability and specifications.
- (3) Shorting output to V⁺ will adversely affect reliability.
- (4) Shorting output to V will adversely affect reliability.
- (5) The maximum power dissipation is a function of T_{J(MAX)}, R_{θJA}. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} T_A)/ R_{θJA}. All numbers apply for packages soldered directly onto a PC Board.

7.2 ESD Ratings - Commercial

			VALUE	UNIT
LMV358	B-N/LMV324-N in all package	s		
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V	
	Electrostatic discharge	Machine model	±100	V
LMV321	-N in all packages			
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±900	\/	
	Electrostatic discharge	Machine model	±100	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 ESD Ratings - Automotive

	LOD Italings Auton			
			VALUE	UNIT
LMV358	3-N-Q1, LMV324-N-Q1 in all p	packages		
V _(ESD) Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V	
	Electrostatic discharge	Machine model	±100	v
LM321-	N-Q1 in all packages			
\/	Flootroptotic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±900	V
$V_{(ESD)}$	Electrostatic discharge	Machine model	±100	V

⁽¹⁾ AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.4 Recommended Operating Conditions

	MIN	MAX	UNIT
Supply Voltage	2.7	5.5	V
Temperature Range ⁽¹⁾ : LMV321-N/LMV358-N/LMV324-N	-40	125	°C

⁽¹⁾ The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A)/R_{\theta JA}$. All numbers apply for packages soldered directly onto a PC Board.

Submit Documentation Feedback

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

7.5 Thermal Information

THERMAL METRIC ⁽¹⁾		LMV321-N, LMV32 LMV321-N-Q1		LMV324-N, LMV324-N-Q1		LMV358-N, LMV358-N-Q1			
		DBV	DCK	D	PW	D	DGK	UNIT	
		5 PINS		14 PINS		8 PINS			
Re	Junction-to-ambient thermal resistance	265	478	145	155	190	235	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

7.6 2.7-V DC Electrical Characteristics

Unless otherwise specified, all limits specified for T_J = 25°C, V^+ = 2.7 V, V^- = 0 V, V_{CM} = 1.0 V, V_O = $V^+/2$ and R_L > 1 M Ω .

	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
Vos	Input Offset Voltage			1.7	7	mV
TCV _{OS}	Input Offset Voltage Average Drift			5		μV/°C
I _B	Input Bias Current			11	250	nA
los	Input Offset Current			5	50	nA
CMRR	Common Mode Rejection Ratio	0 V ≤ V _{CM} ≤ 1.7 V	50	63		dB
PSRR	Power Supply Rejection Ratio	$2.7 \text{ V} \le \text{V}^+ \le 5 \text{ V}$ V _O = 1V	50	60		dB
V _{CM}	Input Common-Mode Voltage Range	For CMRR ≥ 50 dB	0	-0.2		V
				1.9	1.7	V
Vo	Output Swing	$R_L = 10 \text{ k}\Omega \text{ to } 1.35 \text{ V}$	V ⁺ -100	V ⁺ −10		mV
				60	180	mV
I _S	Supply Current	LMV321-N		80	170	μA
'5		LMV358-N Both amplifiers		140	340	μΑ
		LMV324-N All four amplifiers		260	680	μA

⁽¹⁾ All limits are ensured by testing or statistical analysis.

7.7 2.7-V AC Electrical Characteristics

Unless otherwise specified, all limits specified for T $_J$ = 25°C, V⁺ = 2.7 V, V⁻ = 0 V, V $_{CM}$ = 1.0 V, V $_{O}$ = V⁺/2 and R $_{L}$ > 1 M Ω .

	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾ TYP ⁽²⁾	MAX ⁽¹⁾ UNIT
GBWP	Gain-Bandwidth Product	C _L = 200 pF	1	MHz
Φ_{m}	Phase Margin		60	Deg
G _m	Gain Margin		10	dB
e _n	Input-Referred Voltage Noise	f = 1 kHz	46	$\frac{nV}{\sqrt{Hz}}$
i _n	Input-Referred Current Noise	f = 1 kHz	0.17	pA √Hz

¹⁾ All limits are ensured by testing or statistical analysis.

⁽²⁾ Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.

⁽²⁾ Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.



Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1 TEXAS INSTRUMENTS

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

www.ti.com

7.8 5-V DC Electrical Characteristics

Unless otherwise specified, all limits specified for T $_J$ = 25°C, V⁺ = 5 V, V⁻ = 0 V, V_{CM} = 2.0 V, V_O = V⁺/2 and R $_L$ > 1 M Ω .

	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
Vos	Input Offset Voltage			1.7	7	\/
		-40°C ≤ T _J ≤ 125°C			9	mV
TCV _{OS}	Input Offset Voltage Average Drift			5		μV/°C
I _B	Input Bias Current			15	250	nΛ
		–40°C ≤ T _J ≤ 125°C			500	nA
los	Input Offset Current			5	50	nΛ
		-40°C ≤ T _J ≤ 125°C			150	nA
CMRR	Common Mode Rejection Ratio	0 V ≤ V _{CM} ≤ 4 V	50	65		dB
PSRR	Power Supply Rejection Ratio	$2.7 \text{ V} \le \text{V}^+ \le 5 \text{ V}$ V _O = 1V, V _{CM} = 1 V	50	60		dB
V _{CM}	Input Common-Mode Voltage Range	For CMRR ≥ 50 dB	0	-0.2		V
				4.2	4	V
A _V	Large Signal Voltage Gain	$R_L = 2 k\Omega$	15	100		V/mV
	(3)	$R_L = 2 \text{ k}\Omega, -40^{\circ}\text{C} \le T_J \le 125^{\circ}\text{C}$	10			- V/mV
Vo	Output Swing	$R_L = 2 k\Omega$ to 2.5 V	V ⁺ - 300	V ⁺ -40		
		$R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{ V}, -40^{\circ}\text{C} \le T_J \le 125^{\circ}\text{C}$	V ⁺ - 400			
		$R_L = 2 k\Omega$ to 2.5 V		120	300	mV
		$R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{ V}, -40^{\circ}\text{C} \le T_J \le 125^{\circ}\text{C}$			400	
		$R_L = 10 \text{ k}\Omega \text{ to } 2.5 \text{ V}$	V ⁺ - 100	V ⁺ - 10		
		$R_L = 10 \text{ k}\Omega \text{ to } 2.5 \text{ V}, -40^{\circ}\text{C} \le T_J \le 125^{\circ}\text{C}$	V ⁺ - 200			
		$R_L = 2 k\Omega$ to 2.5 V		65	180	
		$R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{ V}, 125^{\circ}\text{C}$			280	
I _O	Output Short Circuit Current	Sourcing, V _O = 0 V	5	60		A
		Sinking, V _O = 5 V	10	160		mA
I _S	Supply Current	LMV321-N		130	250	
		LMV321-N, –40°C ≤ T _J ≤ 125°C			350	
		LMV358-N (both amps)		210	440	
		LMV358-N (both amps), −40°C ≤ T _J ≤ 125°C			615	μΑ
		LMV324-N (all four amps)		410	830	
		LMV324-N (all four amps), −40°C ≤ T _J ≤ 125°C			1160	

⁽¹⁾ All limits are ensured by testing or statistical analysis.

⁽²⁾ Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.

⁽³⁾ R_L is connected to V^- . The output voltage is $0.5 \text{ V} \le V_O \le 4.5 \text{ V}$.



Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

7.9 5-V AC Electrical Characteristics

Unless otherwise specified, all limits specified for $T_J = 25^{\circ}C$, $V^+ = 5$ V, $V^- = 0$ V, $V_{CM} = 2.0$ V, $V_O = V^+/2$ and $R_L > 1$ M Ω .

	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾ TYP ⁽²⁾ MA	XX ⁽¹⁾ UNIT
SR	Slew Rate	(3)	1	V/µs
GBWP	Gain-Bandwidth Product	C _L = 200 pF	1	MHz
Φ_{m}	Phase Margin		60	Deg
G _m	Gain Margin		10	dB
e _n	Input-Referred Voltage Noise	f = 1 kHz	39	<u>nV</u> √Hz
i _n	Input-Referred Current Noise	f = 1 kHz	0.21	pA √Hz

⁽¹⁾ All limits are ensured by testing or statistical analysis.

⁽²⁾ Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.

⁽³⁾ Connected as voltage follower with 3-V step input. Number specified is the slower of the positive and negative slew rates.

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



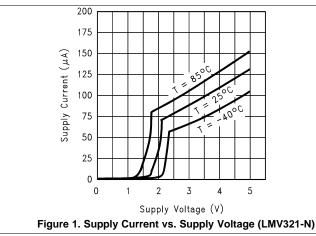




www.ti.com

7.10 Typical Characteristics

Unless otherwise specified, $V_S = 5 \text{ V}$, single supply, $T_A = 25 ^{\circ}\text{C}$.



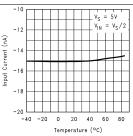
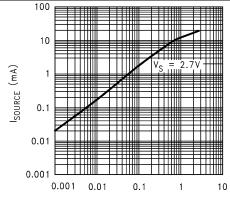


Figure 2. Input Current vs. Temperature



Output Voltage Referenced to V⁺ (V) Figure 3. Sourcing Current vs. Output Voltage

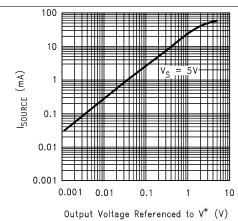
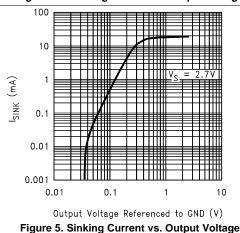


Figure 4. Sourcing Current vs. Output Voltage



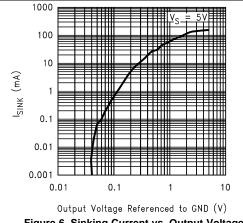


Figure 6. Sinking Current vs. Output Voltage





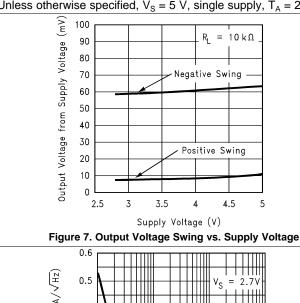
www.ti.com

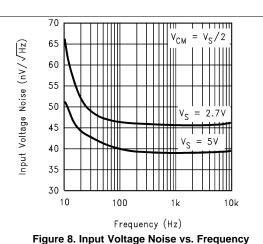
LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

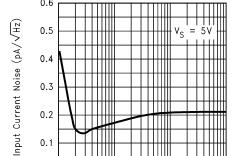
Typical Characteristics (continued)

Unless otherwise specified, $V_S = 5 \text{ V}$, single supply, $T_A = 25^{\circ}\text{C}$





Input Current Noise (pA/VHz) 0.4 0.3 0.2 0.1 0.0 10 100 10k

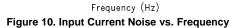


0.1

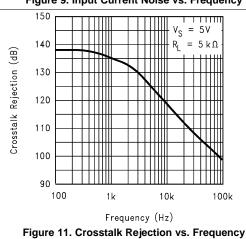
0.0

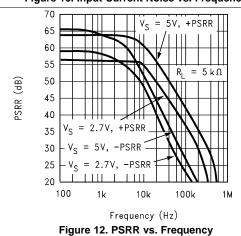
10





100





Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

Typical Characteristics (continued)

Unless otherwise specified, $V_S = 5 \text{ V}$, single supply, $T_A = 25^{\circ}\text{C}$.

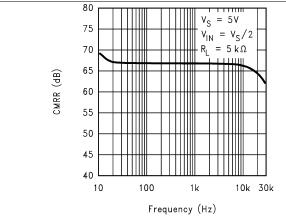


Figure 13. CMRR vs. Frequency

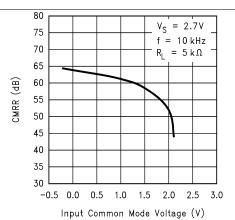


Figure 14. CMRR vs. Input Common Mode Voltage

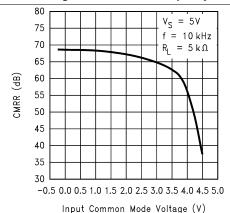


Figure 15. CMRR vs. Input Common Mode Voltage

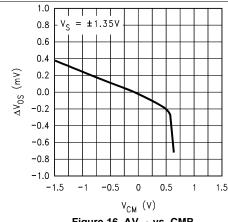
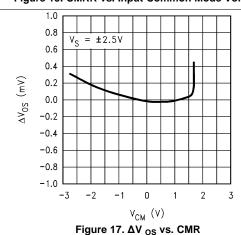


Figure 16. ΔV_{OS} vs. CMR



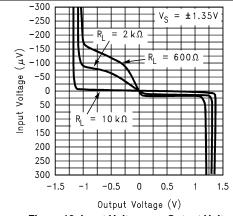


Figure 18. Input Voltage vs. Output Voltage

www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

Typical Characteristics (continued)

Unless otherwise specified, $V_S = 5 \text{ V}$, single supply, $T_A = 25^{\circ}\text{C}$.

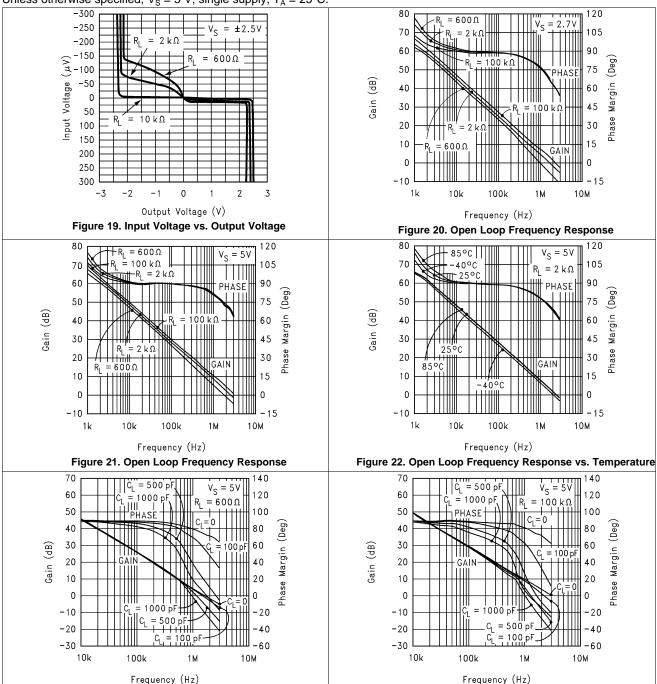


Figure 23. Gain and Phase vs. Capacitive Load

Figure 24. Gain and Phase vs. Capacitive Load

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

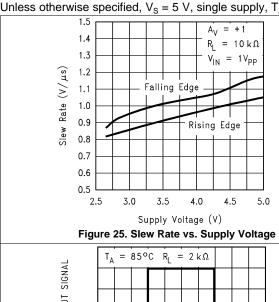


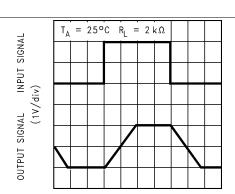
SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

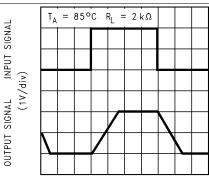
Typical Characteristics (continued)

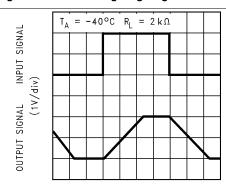
Unless otherwise specified, $V_S = 5 \text{ V}$, single supply, $T_A = 25^{\circ}\text{C}$.





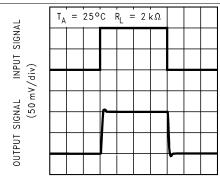
TIME $(1 \mu s/div)$ Figure 26. Non-Inverting Large Signal Pulse Response

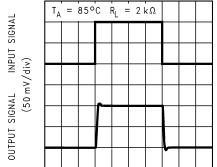




TIME (1 μ s/div) Figure 27. Non-Inverting Large Signal Pulse Response

TIME (1 μ s/div) Figure 28. Non-Inverting Large Signal Pulse Response





TIME $(1 \mu s/div)$ Figure 29. Non-Inverting Small Signal Pulse Response

TIME (1 μ s/div) Figure 30. Non-Inverting Small Signal Pulse Response

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



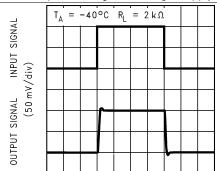
www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

Typical Characteristics (continued)

Unless otherwise specified, $V_S = 5 \text{ V}$, single supply, $T_A = 25 ^{\circ}\text{C}$.



TIME (1 μ s/div)

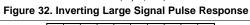
TA = 25°C RL = 2 kΩ

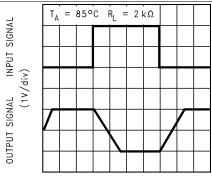
(10/Aiv)

(11/Aiv)

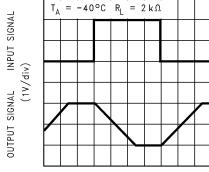
TIME (1 µs/div)

Figure 31. Non-Inverting Small Signal Pulse Response

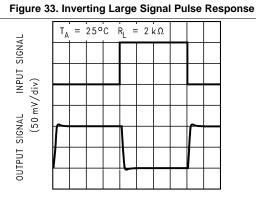




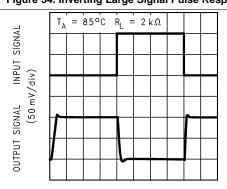
TIME (1 μs/div)



 $\label{eq:time_time} {\sf TIME} \ ({\it 1~\mu s/div})$ Figure 34. Inverting Large Signal Pulse Response



TIME (1 μ s/div) Figure 35. Inverting Small Signal Pulse Response



TIME (1 μ s/div) Figure 36. Inverting Small Signal Pulse Response

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

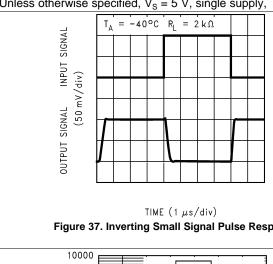


SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

Typical Characteristics (continued)

Unless otherwise specified, $V_S = 5 \text{ V}$, single supply, $T_A = 25^{\circ}\text{C}$.



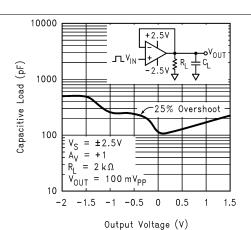
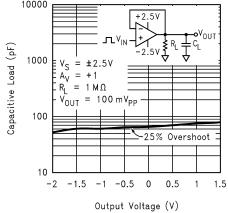
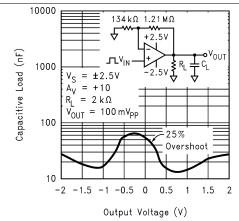


Figure 37. Inverting Small Signal Pulse Response

Figure 38. Stability vs. Capacitive Load





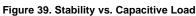
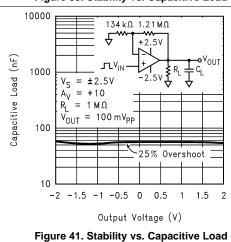
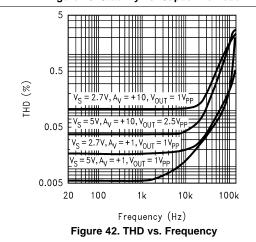


Figure 40. Stability vs. Capacitive Load





Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

Typical Characteristics (continued)

Unless otherwise specified, $V_S = 5 \text{ V}$, single supply, $T_A = 25^{\circ}\text{C}$.

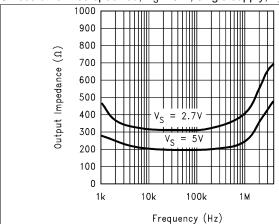


Figure 43. Open Loop Output Impedance vs. Frequency

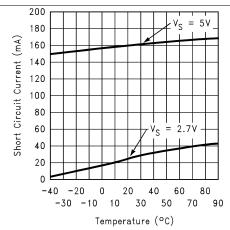


Figure 44. Short Circuit Current vs. Temperature (Sinking)

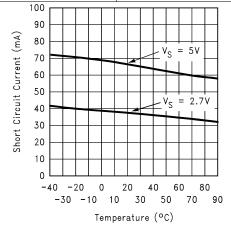


Figure 45. Short Circuit Current vs. Temperature (Sourcing)



Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1 TEXAS INSTRUMENTS

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

www.ti.com

8 Detailed Description

8.1 Overview

The LMV358-N/LMV324-N are low voltage (2.7 V to 5.5 V) versions of the dual and quad commodity op amps LM358/LM324 (5 V to 30 V). The LMV321-N is the single channel version. The LMV321-N/LMV358-N/LMV324-N are the most cost effective solutions for applications where low voltage operation, space efficiency, and low price are important. They offer specifications that meet or exceed the familiar LM358/LM324. The LMV321-N/LMV358-N/LMV324-N have rail-to-rail output swing capability and the input common-mode voltage range includes ground. They all exhibit excellent speed to power ratio, achieving 1 MHz of bandwidth and 1-V/µs slew rate with low supply current.

8.1.1 Benefits of the LMV321-N/LMV358-N/LMV324-N

8.1.1.1 Size

The small footprints of the LMV321-N/LMV358-N/LMV324-N packages save space on printed circuit boards, and enable the design of smaller electronic products, such as cellular phones, pagers, or other portable systems. The low profile of the LMV321-N/LMV358-N/LMV324-N make them possible to use in PCMCIA type III cards.

8.1.1.2 Signal Integrity

Signals can pick up noise between the signal source and the amplifier. By using a physically smaller amplifier package, the LMV321-N/LMV358-N/LMV324-N can be placed closer to the signal source, reducing noise pickup and increasing signal integrity.

8.1.1.3 Simplified Board Layout

These products help you to avoid using long PC traces in your PC board layout. This means that no additional components, such as capacitors and resistors, are needed to filter out the unwanted signals due to the interference between the long PC traces.

8.1.1.4 Low Supply Current

These devices will help you to maximize battery life. They are ideal for battery powered systems.

8.1.1.5 Low Supply Voltage

Texas Instruments provides ensured performance at 2.7 V and 5 V. These specifications ensure operation throughout the battery lifetime.

8.1.1.6 Rail-to-Rail Output

Rail-to-rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating on low supply voltages.

8.1.1.7 Input Includes Ground

Allows direct sensing near GND in single supply operation.

Protection should be provided to prevent the input voltages from going negative more than -0.3V (at 25°C). An input clamp diode with a resistor to the IC input terminal can be used.

8.1.1.8 Ease of Use and Crossover Distortion

The LMV321-N/LMV358-N/LMV324-N offer specifications similar to the familiar LM324-N. In addition, the new LMV321-N/LMV358-N/LMV324-N effectively eliminate the output crossover distortion. The scope photos in Figure 46 and Figure 47 compare the output swing of the LMV324-N and the LM324-N in a voltage follower configuration, with $V_S = \pm 2.5 V$ and R_L (= 2 k Ω) connected to GND. It is apparent that the crossover distortion has been eliminated in the new LMV324-N.

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

Overview (continued)

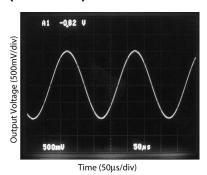


Figure 46. Output Swing of LMV324

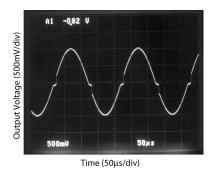


Figure 47. Output Swing of LM324

8.2 Functional Block Diagram

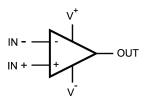


Figure 48. Each Amplifier

8.3 Feature Description

8.3.1 Capacitive Load Tolerance

The LMV321-N/LMV358-N/LMV324-N can directly drive 200 pF in unity-gain without oscillation. The unity-gain follower is the most sensitive configuration to capacitive loading. Direct capacitive loading reduces the phase margin of amplifiers. The combination of the amplifier's output impedance and the capacitive load induces phase lag. This results in either an underdamped pulse response or oscillation. To drive a heavier capacitive load, the circuit in Figure 49 can be used.

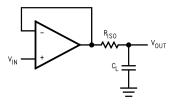


Figure 49. Indirectly Driving a Capacitive Load Using Resistive Isolation

In Figure 49 , the isolation resistor R_{ISO} and the load capacitor C_L form a pole to increase stability by adding more phase margin to the overall system. The desired performance depends on the value of R_{ISO} . The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. Figure 50 is an output waveform of Figure 49 using 620Ω for R_{ISO} and 510 pF for C_L .

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

Feature Description (continued)

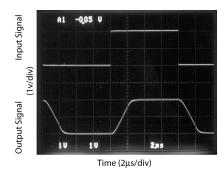


Figure 50. Pulse Response of the LMV324 Circuit in Figure 49

The circuit in Figure 51 is an improvement to the one in Figure 49 because it provides DC accuracy as well as AC stability. If there were a load resistor in Figure 49, the output would be voltage divided by $R_{\rm ISO}$ and the load resistor. Instead, in Figure 51, $R_{\rm F}$ provides the DC accuracy by using feed-forward techniques to connect $V_{\rm IN}$ to $R_{\rm L}$. Caution is needed in choosing the value of $R_{\rm F}$ due to the input bias current of theLMV321-N/LMV358-N/LMV324-N. $C_{\rm F}$ and $R_{\rm ISO}$ serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop. Increased capacitive drive is possible by increasing the value of $C_{\rm F}$. This in turn will slow down the pulse response.

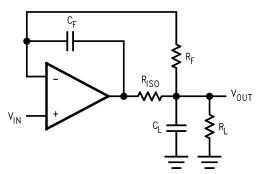


Figure 51. Indirectly Driving A Capacitive Load with DC Accuracy

8.3.2 Input Bias Current Cancellation

The LMV321-N/LMV358-N/LMV324-N family has a bipolar input stage. The typical input bias current of LMV321-N/LMV358-N/LMV324-N is 15 nA with 5V supply. Thus a 100 k Ω input resistor will cause 1.5 mV of error voltage. By balancing the resistor values at both inverting and non-inverting inputs, the error caused by the amplifier's input bias current will be reduced. The circuit in Figure 52 shows how to cancel the error caused by input bias current.

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

Feature Description (continued)

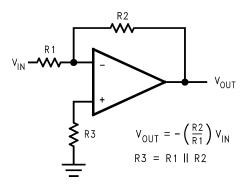


Figure 52. Cancelling the Error Caused by Input Bias Current

8.4 Device Functional Modes

The LMV321-N/LMV321-N-Q1/LMV358-N/LMV358-N-Q1/LMV324-N/LMV324-N-Q1 are powered on when the supply is connected. They can be operated as a single supply or a dual supply operational amplifier depending on the application.

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The LMV32x-N family of amplifiers is specified for operation from 2.7 V to 5 V (±1.35 V to ±2.5 V). Many of the specifications apply from –40°C to 125°C. They provide ground-sensing inputs as well as rail-to-rail output swing. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics*.

9.2 Typical Applications

9.2.1 Simple Low-Pass Active Filter

A simple active low-pass filter is shown in Figure 53.

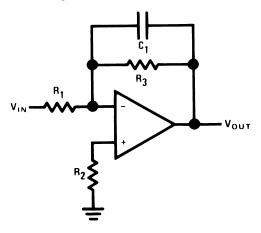


Figure 53. Simple Low-Pass Active Filter

9.2.1.1 Design Requirements

The simple single pole active lowpass filter shown in Figure 53 will pass low frequencies and attenuate frequencies above corner frequency (fc) at a roll-off rate of 20dB/Decade.

9.2.1.2 Detailed Design Procedure

The values of R1, R2, R3 and C1 are selected using the formulas in Figure 54. The low-frequency gain ($\omega \to 0$) is defined by $-R_3/R_1$. This allows low-frequency gains other than unity to be obtained. The filter has a -20 dB/decade roll-off after its corner frequency fc. R_2 should be chosen equal to the parallel combination of R_1 and R_3 to minimize errors due to bias current. The frequency response of the filter is shown in Figure 55.

$$A_{L} = -\frac{R_{3}}{R_{1}}$$

$$f_{c} = \frac{1}{2\pi R_{3} C_{1}}$$

$$R_{2} = R_{1} || R_{3}$$

Figure 54. Simple Low-Pass Active Filter Equations

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

Typical Applications (continued)

9.2.1.3 Application Curves

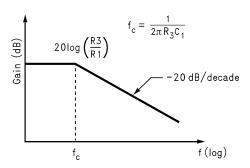


Figure 55. Frequency Response of Simple Low-Pass Active Filter

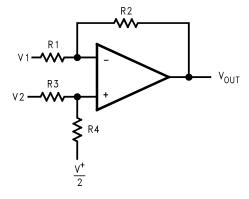
Note that the single-op-amp active filters are used in the applications that require low quality factor, $Q(\le 10)$, low frequency (≤ 5 kHz), and low gain (≤ 10), or a small value for the product of gain times $Q(\le 100)$. The op amp should have an open loop voltage gain at the highest frequency of interest at least 50 times larger than the gain of the filter at this frequency. In addition, the selected op amp should have a slew rate that meets the following requirement:

Slew Rate
$$\geq 0.5 \times (\omega_H V_{OPP}) \times 10^{-6} V/\mu sec$$
 (1)

where ω_H is the highest frequency of interest, and V_{OPP} is the output peak-to-peak voltage.

9.2.2 Difference Amplifier

The difference amplifier allows the subtraction of two voltages or, as a special case, the cancellation of a signal common to two inputs. It is useful as a computational amplifier, in making a differential to single-ended conversion or in rejecting a common mode signal.



$$\begin{split} &V_{OUT} = \left(\frac{R1 + R2}{R3 + R4}\right)\frac{R4}{R1}V_2 - \frac{R2}{R1}V_1 + \left(\frac{R1 + R2}{R3 + R4}\right)\frac{R3}{R1} \bullet \frac{V^+}{2} \\ &\text{for R1} = R3 \text{ and } R2 = R4 \\ &V_{OUT} = \frac{R2}{R1}\left(V_2 - V_1\right) + \frac{V^+}{2} \end{split}$$

Figure 56. Difference Amplifier

9.2.3 Instrumentation Circuits

The input impedance of the previous difference amplifier is set by the resistors R_1 , R_2 , R_3 , and R_4 . To eliminate the problems of low input impedance, one way is to use a voltage follower ahead of each input as shown in the following two instrumentation amplifiers.

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

Typical Applications (continued)

9.2.3.1 Three-Op-Amp Instrumentation Amplifier

The quad LMV324 can be used to build a three-op-amp instrumentation amplifier as shown in Figure 57.

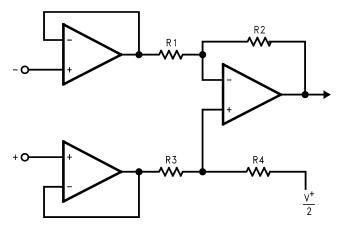


Figure 57. Three-Op-Amp Instrumentation Amplifier

The first stage of this instrumentation amplifier is a differential-input, differential-output amplifier, with two voltage followers. These two voltage followers assure that the input impedance is over 100 M Ω . The gain of this instrumentation amplifier is set by the ratio of R_2/R_1 . R_3 should equal R_1 , and R_4 equal R_2 . Matching of R_3 to R_1 and R_4 to R_2 affects the CMRR. For good CMRR over temperature, low drift resistors should be used. Making R_4 slightly smaller than R_2 and adding a trim pot equal to twice the difference between R_2 and R_4 will allow the CMRR to be adjusted for optimum performance.

9.2.3.2 Two-Op-Amp Instrumentation Amplifier

A two-op-amp instrumentation amplifier can also be used to make a high-input-impedance DC differential amplifier (Figure 58). As in the three-op-amp circuit, this instrumentation amplifier requires precise resistor matching for good CMRR. R_4 should equal R_1 and, R_3 should equal R_2 .

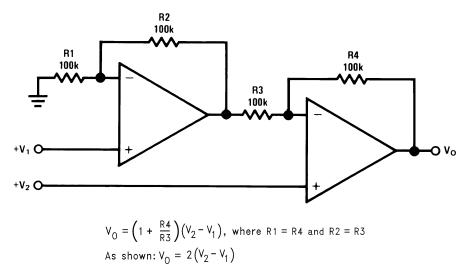


Figure 58. Two-Op-Amp Instrumentation Amplifier

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

Typical Applications (continued)

9.2.3.3 Single-Supply Inverting Amplifier

There may be cases where the input signal going into the amplifier is negative. Because the amplifier is operating in single supply voltage, a voltage divider using R_3 and R_4 is implemented to bias the amplifier so the input signal is within the input common-mode voltage range of the amplifier. The capacitor C_1 is placed between the inverting input and resistor R_1 to block the DC signal going into the AC signal source, V_{IN} . The values of R_1 and C_1 affect the cutoff frequency, fc = $1/2\pi R_1 C_1$.

As a result, the output signal is centered around mid-supply (if the voltage divider provides $V^+/2$ at the non-inverting input). The output can swing to both rails, maximizing the signal-to-noise ratio in a low voltage system.

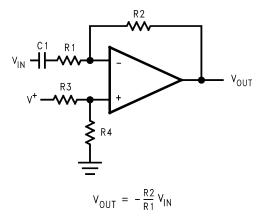


Figure 59. Single-Supply Inverting Amplifier

9.2.4 Sallen-Key 2nd-Order Active Low-Pass Filter

The Sallen-Key 2nd-order active low-pass filter is illustrated in Figure 60. The DC gain of the filter is expressed as

$$A_{LP} = \frac{R_3}{R_4} + 1 \tag{2}$$

Its transfer function is

 $\frac{V_{OUT}}{V_{IN}}(s) = \frac{\frac{1}{C_1 C_2 R_1 R_2} A_{LP}}{s^2 + s \left(\frac{1}{C_1 R_1} + \frac{1}{C_1 R_2} + \frac{1}{C_2 R_2} - \frac{A_{LP}}{C_2 R_2}\right) + \frac{1}{C_1 C_2 R_1 R_2}}{s^2 + s \left(\frac{1}{C_1 R_1} + \frac{1}{C_1 R_2} + \frac{1}{C_2 R_2} - \frac{A_{LP}}{C_2 R_2}\right) + \frac{1}{C_1 C_2 R_1 R_2}}$ $V_{IN} = \frac{c_1}{0.01 \mu F}$ $V_{IN} = \frac{c_2}{0.01 \mu F}$ $0.01 \mu F$ $0.01 \mu F$

Figure 60. Sallen-Key 2nd-Order Active Low-Pass Filter

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

Typical Applications (continued)

9.2.4.1 Detailed Design Procedure

The following paragraphs explain how to select values for R_1 , R_2 , R_3 , R_4 , C_1 , and C_2 for given filter requirements, such as A_{LP} , Q, and f_c .

The standard form for a 2nd-order low pass filter is

$$\frac{V_{OUT}}{V_{IN}}(S) = \frac{A_{LP}\omega_c^2}{S^2 + (\frac{\omega_c}{Q})S + \omega_c^2}$$
(4)

where

Q: Pole Quality Factor

ω_C: Corner Frequency

A comparison between Equation 3 and Equation 4 yields

$$\omega_{c}^{2} = \frac{1}{C_{1} C_{2} R_{1} R_{2}}$$
 (5)

$$\frac{\omega_{\rm C}}{Q} = \frac{1}{C_1 R_1} + \frac{1}{C_1 R_2} + \frac{1}{C_2 R_2} - \frac{A_{\rm LP}}{C_2 R_2} \tag{6}$$

To reduce the required calculations in filter design, it is convenient to introduce normalization into the components and design parameters. To normalize, let $\omega_C = \omega_n = 1$ rad/s, and $C_1 = C_2 = C_n = 1$ F, and substitute these values into Equation 5 and Equation 6. From Equation 5, we obtain

$$R_1 = \frac{1}{R_2} \tag{7}$$

From Equation 6, we obtain

$$R_2 = \frac{1 \pm \sqrt{1 - 4Q^2(2 - A_{LP})}}{2Q} \tag{8}$$

For minimum DC offset, $V^+ = V^-$, the resistor values at both inverting and non-inverting inputs should be equal, which means

$$R_1 + R_2 = \frac{R_3 R_4}{R_3 + R_4} \tag{9}$$

From Equation 2 and Equation 9, we obtain

$$R_3 = (R_1 + R_2)A_{LP}$$
 (10)

$$R_4 = \left(\frac{A_{LP}}{A_{LP}-1}\right) (R_1 + R_2) \tag{11}$$

The values of C₁ and C₂ are normally close to or equal to

$$C = \frac{10}{f_c} \mu F \tag{12}$$

As a design example:

Require: $A_{LP} = 2$, Q = 1, fc = 1 kHz

Start by selecting C₁ and C₂. Choose a standard value that is close to

$$C = \frac{10}{f_c} \mu F \tag{13}$$

$$C_1 = C_2 = \frac{10}{1 \times 10^3} \, \mu F = 0.01 \, \mu F$$
 (14)

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

Typical Applications (continued)

From Equation 7, Equation 8, Equation 10, and Equation 11,

$$R_1 = 1\Omega \tag{15}$$

$$R_2 = 1\Omega \tag{16}$$

$$R_3 = 4\Omega \tag{17}$$

$$R_4 = 4\Omega \tag{18}$$

The above resistor values are normalized values with $\omega_n = 1$ rad/s and $C_1 = C_2 = C_n = 1$ F. To scale the normalized cutoff frequency and resistances to the real values, two scaling factors are introduced, frequency scaling factor (k_f) and impedance scaling factor (k_m).

$$k_f = \frac{\omega_c}{\omega_n} = \frac{2\pi \times 1 \times 10^3}{1} = 2\pi \times 10^3$$

$$k_m k_f = \frac{Cn}{C1}$$

$$k_{\rm m} = 1.59 \times 10^4$$
 (19)

Scaled values:

$$R_2 = R_1 = 15.9 \text{ k}\Omega$$
 (20)

$$R_3 = R_4 = 63.6 \text{ k}\Omega$$
 (21)

$$C_1 = C_2 = 0.01 \,\mu\text{F}$$
 (22)

An adjustment to the scaling may be made in order to have realistic values for resistors and capacitors. The actual value used for each component is shown in the circuit.

9.2.5 2nd-Order High Pass Filter

A 2nd-order high pass filter can be built by simply interchanging those frequency selective components (R_1 , R_2 , C_1 , C_2) in the Sallen-Key 2nd-order active low pass filter. As shown in Figure 61, resistors become capacitors, and capacitors become resistors. The resulted high pass filter has the same corner frequency and the same maximum gain as the previous 2nd-order low pass filter if the same components are chosen.

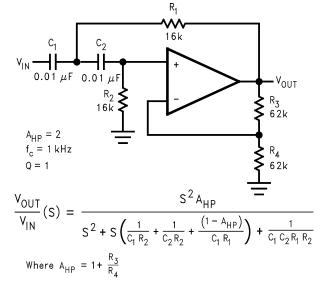


Figure 61. Sallen-Key 2nd-Order Active High-Pass Filter

9.2.6 State Variable Filter

A state variable filter requires three op amps. One convenient way to build state variable filters is with a quad op amp, such as the LMV324 (Figure 62).

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

Typical Applications (continued)

This circuit can simultaneously represent a low-pass filter, high-pass filter, and bandpass filter at three different outputs. The equations for these functions are listed below. It is also called "Bi-Quad" active filter as it can produce a transfer function which is quadratic in both numerator and denominator.

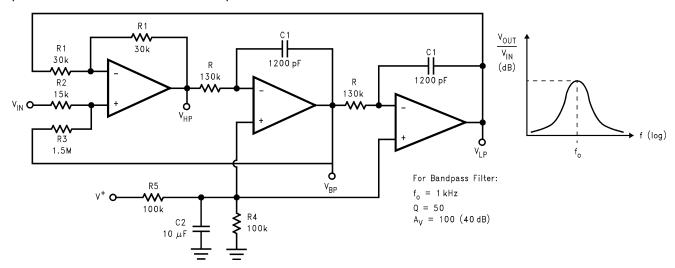


Figure 62. State Variable Active Filter

$$V_{LP} = \left(\frac{2R_3}{R_2 + R_3}\right) \frac{\frac{1}{R^2C^2}}{S^2 + \frac{1}{\left(\frac{R_2 + R_3}{2R_2}\right)RC}S + \frac{1}{R^2C^2}} V_{IN}$$

$$V_{HP} = \left(\frac{2R_3}{R_2 + R_3}\right) \frac{S^2}{S^2 + \frac{1}{\left(\frac{R_2 + R_3}{2R_2}\right)RC}} S + \frac{1}{R^2C^2} V_{IN}$$

$$V_{BP} = \left(\frac{2R_3}{R_2 + R_3}\right) \frac{\left(\frac{1}{RC}\right)S}{S^2 + \frac{1}{\left(\frac{R_2 + R_3}{2R_2}\right)RC}S + \frac{1}{R^2C^2}} V_{IN}$$

where for all three filters,

$$Q = \frac{R_2 + R_3}{2R_2} \tag{24}$$

$$\omega_0 = \frac{1}{RC}$$
 (resonant frequency) (25)

9.2.6.1 Detailed Design Procedure

Assume the system design requires a bandpass filter with $f_0 = 1$ kHz and Q = 50. What needs to be calculated are capacitor and resistor values.

First choose convenient values for C₁, R₁ and R₂:

$$C_1 = 1200 \text{ pF}$$
 (26)

(23)

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

Typical Applications (continued)

$$2R_2 = R_1 = 30 \text{ k}\Omega \tag{27}$$

Then from Equation 24,

$$R_3 = R_2(2Q-1)$$

 $R_3 = 15 k\Omega \times (2 \times 50-1)$

 $= 1.5 \,\mathrm{M}\,\Omega \tag{28}$

From Equation 25,

$$R = \frac{1}{\omega_0 C_1}$$

$$R = \frac{1}{(2\pi \times 10^3)(1.2 \times 10^{-9})}$$

$$= 132.7 \text{ k}\Omega$$

= 132.7 k Ω (29)

From the above calculated values, the midband gain is $H_0 = R_3/R_2 = 100$ (40 dB). The nearest 5% standard values have been added to Figure 62.

9.2.7 Pulse Generators and Oscillators

A pulse generator is shown in Figure 63. Two diodes have been used to separate the charge and discharge paths to capacitor C.

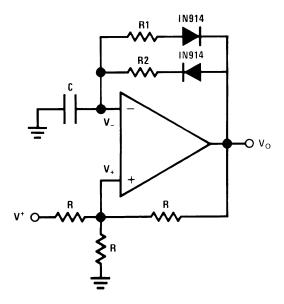


Figure 63. Pulse Generator

When the output voltage V_O is first at its high, V_{OH} , the capacitor C is charged toward V_{OH} through R_2 . The voltage across C rises exponentially with a time constant $\tau=R_2C$, and this voltage is applied to the inverting input of the op amp. Meanwhile, the voltage at the non-inverting input is set at the positive threshold voltage (V_{TH+}) of the generator. The capacitor voltage continually increases until it reaches V_{TH+} , at which point the output of the generator will switch to its low, V_{OL} which 0V is in this case. The voltage at the non-inverting input is switched to the negative threshold voltage (V_{TH-}) of the generator. The capacitor then starts to discharge toward V_{OL} exponentially through R_1 , with a time constant $\tau=R_1C$. When the capacitor voltage reaches V_{TH-} , the output of the pulse generator switches to V_{OH} . The capacitor starts to charge, and the cycle repeats itself.

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

Typical Applications (continued)

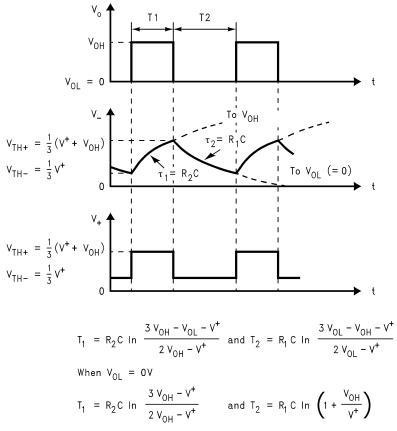


Figure 64. Waveforms of the Circuit in Figure 16

As shown in the waveforms in Figure 64, the pulse width (T_1) is set by R_2 , C and V_{OH} , and the time between pulses (T_2) is set by R_1 , C and V_{OL} . This pulse generator can be made to have different frequencies and pulse width by selecting different capacitor value and resistor values.

Figure 65 shows another pulse generator, with separate charge and discharge paths. The capacitor is charged through R_1 and is discharged through R_2 .

www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

Typical Applications (continued)

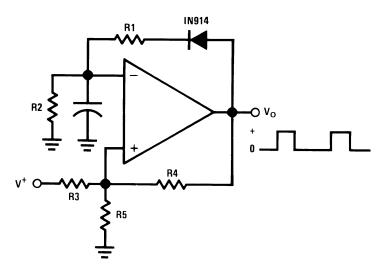


Figure 65. Pulse Generator

Figure 66 is a squarewave generator with the same path for charging and discharging the capacitor.

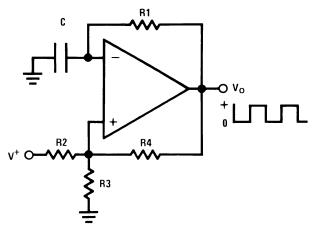


Figure 66. Squarewave Generator

9.2.8 Current Source and Sink

The LMV321-N/LMV358-N/LMV324-N can be used in feedback loops which regulate the current in external PNP transistors to provide current sources or in external NPN transistors to provide current sinks.

9.2.8.1 Fixed Current Source

A multiple fixed current source is shown in Figure 67. A voltage ($V_{REF} = 2V$) is established across resistor R_3 by the voltage divider (R_3 and R_4). Negative feedback is used to cause the voltage drop across R_1 to be equal to V_{REF} . This controls the emitter current of transistor Q_1 and if we neglect the base current of Q_1 and Q_2 , essentially this same current is available out of the collector of Q_1 .

Large input resistors can be used to reduce current loss and a Darlington connection can be used to reduce errors due to the β of Q_1 .

The resistor, R₂, can be used to scale the collector current of Q₂ either above or below the 1 mA reference value.

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J – AUGUST 2000 – REVISED DECEMBER 2014 www.ti.com

Typical Applications (continued)

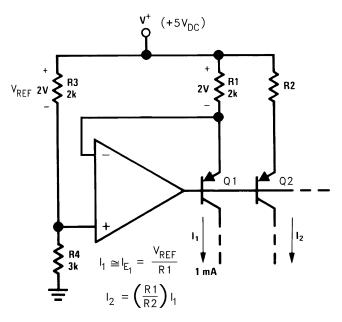


Figure 67. Fixed Current Source

9.2.8.2 High Compliance Current Sink

A current sink circuit is shown in Figure 68. The circuit requires only one resistor (R_E) and supplies an output current which is directly proportional to this resistor value.

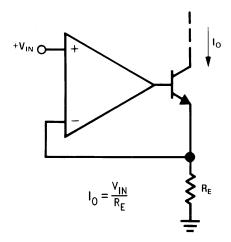


Figure 68. High Compliance Current Sink

9.2.9 Power Amplifier

A power amplifier is illustrated in Figure 69. This circuit can provide a higher output current because a transistor follower is added to the output of the op amp.

www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

Typical Applications (continued)

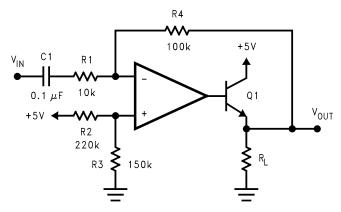


Figure 69. Power Amplifier

9.2.10 LED Driver

The LMV321-N/LMV358-N/LMV324-N can be used to drive an LED as shown in Figure 70.

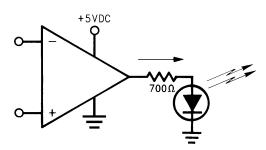


Figure 70. LED Driver

9.2.11 Comparator With Hysteresis

The LMV321-N/LMV358-N/LMV324-N can be used as a low power comparator. Figure 71 shows a comparator with hysteresis. The hysteresis is determined by the ratio of the two resistors.

$$V_{TH+} = V_{REF}/(1+R_1/R_2) + V_{OH}/(1+R_2/R_1)$$
(30)

$$V_{TH-} = V_{REF}/(1+R_1/R_2)+V_{OL}/(1+R_2/R_1)$$
(31)

$$V_{H} = (V_{OH} - V_{OL})/(1 + R_{2}/R_{1})$$
(32)

where

V_{TH+}: Positive Threshold Voltage

V_{TH}-: Negative Threshold Voltage

V_{OH}: Output Voltage at High

V_{OL}: Output Voltage at Low

V_H: Hysteresis Voltage

Since LMV321-N/LMV358-N/LMV324-N have rail-to-rail output, the $(V_{OH-}V_{OL})$ is equal to V_S , which is the supply voltage.

$$V_{H} = V_{S}/(1 + R_{2}/R_{1}) \tag{33}$$

The differential voltage at the input of the op amp should not exceed the specified absolute maximum ratings. For real comparators that are much faster, we recommend you use Texas Instruments's LMV331/LMV93/LMV339, which are single, dual and quad general purpose comparators for low voltage operation.

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

Typical Applications (continued)

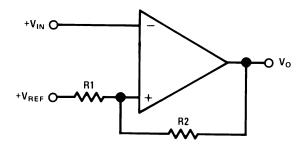


Figure 71. Comparator with Hysteresis

10 Power Supply Recommendations

The LMV3xx-N is specified for operation from 2.7 V to 5.5 V; many specifications apply from –40°C to 125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics*.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high impedance power supplies. For more detailed information on bypass capacitor placement, refer to the *Layout Guidelines* section.

11 Layout

11.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the operational
 amplifier. Bypass capacitors are used to reduce the coupled noise by providing low impedance power
 sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective
 methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes.
 A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital
 and analog grounds, paying attention to the flow of the ground current. For more detailed information, refer to
 Circuit Board Layout Techniques, SLOA089.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting input minimizes parasitic capacitance, as shown in Layout Example.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.



www.ti.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1

SNOS012J - AUGUST 2000 - REVISED DECEMBER 2014

11.2 Layout Example

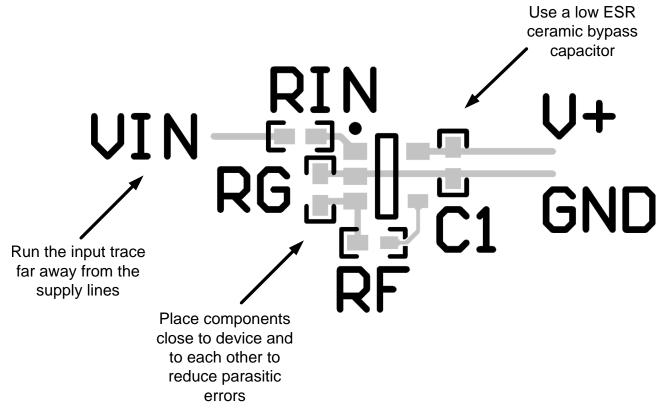


Figure 72. Operational Amplifier Board Layout for Noninverting Configuration

Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

LMV321-N, LMV321-N-Q1, LMV358-N LMV358-N-Q1, LMV324-N, LMV324-N-Q1



SNOS012J-AUGUST 2000-REVISED DECEMBER 2014

www.ti.com

12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LMV321-N	Click here	Click here	Click here	Click here	Click here
LMV321-N-Q1	Click here	Click here	Click here	Click here	Click here
LMV358-N	Click here	Click here	Click here	Click here	Click here
LMV358-N-Q1	Click here	Click here	Click here	Click here	Click here
LMV324-N	Click here	Click here	Click here	Click here	Click here
LMV324-N-Q1	Click here	Click here	Click here	Click here	Click here

12.2 Trademarks

All trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

34 Submit Documentation Feedback Copyright © 2000-2014. Texas Instruments Incorporated

Product Folder Links: LMV321-N LMV321-N-Q1 LMV358-N LMV358-N-Q1 LMV324-N LMV324-N-Q1



Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com
PACKAGE OPTION ADDENDUM

29-Dec-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LMV321M5	NRND	SOT-23	DBV	5	1000	TBD	Call TI	Call TI	-40 to 85	A13	
LMV321M5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A13	Samples
LMV321M5X	NRND	SOT-23	DBV	5		TBD	Call TI	Call TI	-40 to 85	A13	
LMV321M5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A13	Samples
LMV321M7	NRND	SC70	DCK	5	1000	TBD	Call TI	Call TI	-40 to 85	A12	
LMV321M7/NOPB	ACTIVE	SC70	DCK	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A12	Samples
LMV321M7X	NRND	SC70	DCK	5	3000	TBD	Call TI	Call TI	-40 to 85	A12	
LMV321M7X/NOPB	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A12	Samples
LMV321Q1M5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	AYA	Samples
LMV321Q1M5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	AYA	Samples
LMV321Q3M5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	AZA	Samples
LMV321Q3M5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	AZA	Samples
LMV324M	NRND	SOIC	D	14	55	TBD	Call TI	Call TI	-40 to 85	LMV324M	
LMV324M/NOPB	ACTIVE	SOIC	D	14	55	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV324M	Samples
LMV324MT/NOPB	ACTIVE	TSSOP	PW	14	94	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	LMV324 MT	Samples
LMV324MTX	NRND	TSSOP	PW	14	2500	TBD	Call TI	Call TI	-40 to 85	LMV324 MT	
LMV324MTX/NOPB	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	LMV324 MT	Samples
LMV324MX	NRND	SOIC	D	14	2500	TBD	Call TI	Call TI	-40 to 85	LMV324M	
LMV324MX/NOPB	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV324M	Samples

Addendum-Page 1



Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com
PACKAGE OPTION ADDENDUM

29-Dec-2015

Orderable Device	Status	Package Type		Pins		Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LMV324Q1MA/NOPB	ACTIVE	SOIC	D	14	55	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV324Q1 MA	Samples
LMV324Q1MAX/NOPB	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV324Q1 MA	Samples
LMV324Q1MT/NOPB	ACTIVE	TSSOP	PW	14	94	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV324 Q1MT	Samples
LMV324Q1MTX/NOPB	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV324 Q1MT	Samples
LMV324Q3MA/NOPB	ACTIVE	SOIC	D	14	55	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV324Q3 MA	Samples
LMV324Q3MAX/NOPB	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV324Q3 MA	Samples
LMV324Q3MT/NOPB	ACTIVE	TSSOP	PW	14	94	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV324 Q3MT	Samples
LMV324Q3MTX/NOPB	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV324 Q3MT	Samples
LMV358M	NRND	SOIC	D	8	95	TBD	Call TI	Call TI	-40 to 85	LMV 358M	
LMV358M/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV 358M	Samples
LMV358MM	NRND	VSSOP	DGK	8	1000	TBD	Call TI	Call TI	-40 to 85	V358	
LMV358MM/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	V358	Samples
LMV358MMX/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	V358	Samples
LMV358MX	NRND	SOIC	D	8	2500	TBD	Call TI	Call TI	-40 to 85	LMV 358M	
LMV358MX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV 358M	Samples
LMV358Q1MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV35 8Q1MA	Samples
LMV358Q1MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	LMV35 8Q1MA	Samples
LMV358Q1MM/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	AFAA	Samples

Addendum-Page 2



Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

PACKAGE OPTION ADDENDUM

29-Dec-2015

Orderable Device	Status	Package Type		Pins		Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)		Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LMV358Q1MMX/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	AFAA	Samples
LMV358Q3MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV35 8Q3MA	Samples
LMV358Q3MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV35 8Q3MA	Samples
LMV358Q3MM/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	AHAA	Samples
LMV358Q3MMX/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	AHAA	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, Tl Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above

Green (RoHS & no Sb/Br): TI defines "Green* to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(6) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width

Addendum-Page 3



Distributor of Texas Instruments: Excellent Integrated System LimitedDatasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

PACKAGE OPTION ADDENDUM

www.ti.com 29-Dec-2015

Important Information and Disclaimer: The information provided on this page represents Tl's knowledge and belief as of the date that it is provided. Tl bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. Tl has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. Tl and Tl suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LMV321-N, LMV321-N-Q1, LMV324-N, LMV324-N-Q1, LMV358-N, LMV358-N-Q1:

- ◆ Catalog: LMV321-N, LMV324-N, LMV358-N
- Automotive: LMV321-N-Q1, LMV324-N-Q1, LMV358-N-Q1

NOTE: Qualified Version Definitions:

- . Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects

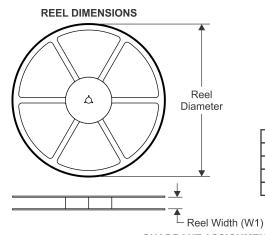
Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

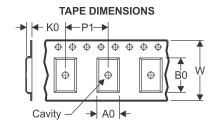


PACKAGE MATERIALS INFORMATION

www.ti.com 30-Dec-2015

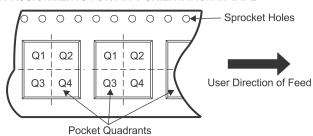
TAPE AND REEL INFORMATION





- A0 Dimension designed to accommodate the component width
- B0 Dimension designed to accommodate the component length
- K0 Dimension designed to accommodate the component thickness
- W Overall width of the carrier tape
- P1 Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV321M5	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321M5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321M5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321M7	SC70	DCK	5	1000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV321M7/NOPB	SC70	DCK	5	1000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV321M7X	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV321M7X/NOPB	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV321Q1M5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321Q1M5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321Q3M5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321Q3M5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV324MTX	TSSOP	PW	14	2500	330.0	12.4	6.95	5.6	1.6	8.0	12.0	Q1
LMV324MTX/NOPB	TSSOP	PW	14	2500	330.0	12.4	6.95	5.6	1.6	8.0	12.0	Q1
LMV324MX	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LMV324MX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LMV324Q1MAX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LMV324Q1MTX/NOPB	TSSOP	PW	14	2500	330.0	12.4	6.95	5.6	1.6	8.0	12.0	Q1
LMV324Q3MAX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1

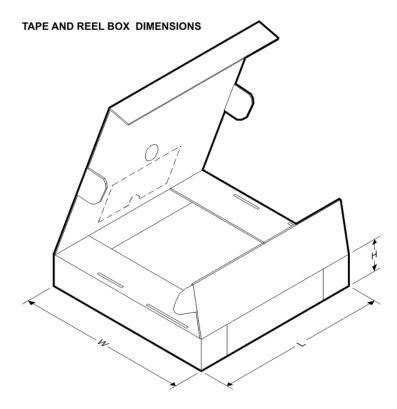
Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



PACKAGE MATERIALS INFORMATION

www.ti.com 30-Dec-2015

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV324Q3MTX/NOPB	TSSOP	PW	14	2500	330.0	12.4	6.95	5.6	1.6	8.0	12.0	Q1
LMV358MM	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358MM/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358MX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMV358MX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMV358Q1MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMV358Q1MM/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358Q1MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358Q3MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMV358Q3MM/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358Q3MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV321M5	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMV321M5/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMV321M5X/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV321M7	SC70	DCK	5	1000	210.0	185.0	35.0
LMV321M7/NOPB	SC70	DCK	5	1000	210.0	185.0	35.0



Datasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



PACKAGE MATERIALS INFORMATION

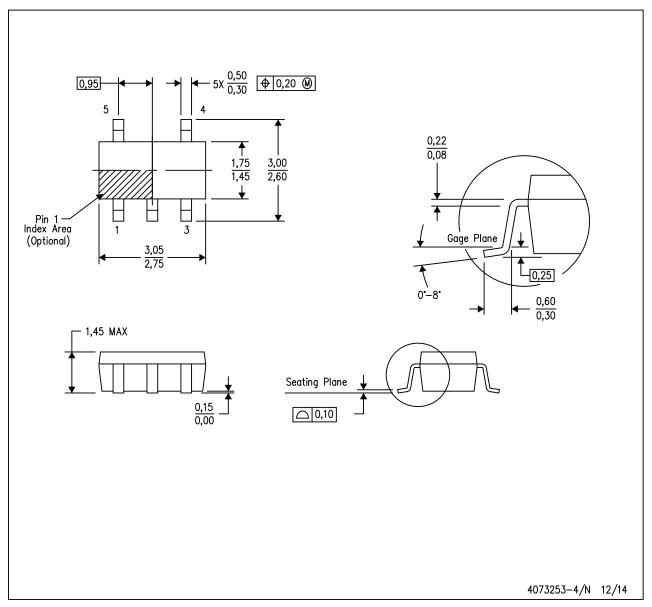
www.ti.com 30-Dec-2015

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV321M7X	SC70	DCK	5	3000	210.0	185.0	35.0
LMV321M7X/NOPB	SC70	DCK	5	3000	210.0	185.0	35.0
LMV321Q1M5/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMV321Q1M5X/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV321Q3M5/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMV321Q3M5X/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV324MTX	TSSOP	PW	14	2500	367.0	367.0	35.0
LMV324MTX/NOPB	TSSOP	PW	14	2500	367.0	367.0	35.0
LMV324MX	SOIC	D	14	2500	367.0	367.0	35.0
LMV324MX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0
LMV324Q1MAX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0
LMV324Q1MTX/NOPB	TSSOP	PW	14	2500	367.0	367.0	35.0
LMV324Q3MAX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0
LMV324Q3MTX/NOPB	TSSOP	PW	14	2500	367.0	367.0	35.0
LMV358MM	VSSOP	DGK	8	1000	210.0	185.0	35.0
LMV358MM/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
LMV358MMX/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0
LMV358MX	SOIC	D	8	2500	367.0	367.0	35.0
LMV358MX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LMV358Q1MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LMV358Q1MM/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
LMV358Q1MMX/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0
LMV358Q3MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LMV358Q3MM/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
LMV358Q3MMX/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0



DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



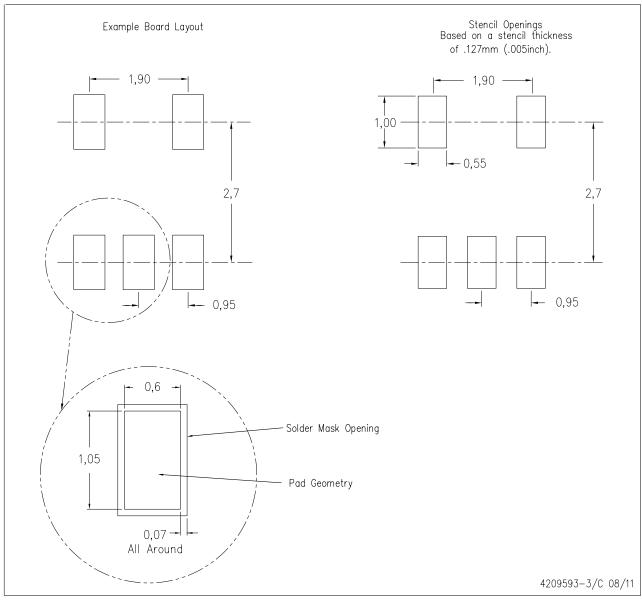
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-178 Variation AA.





DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



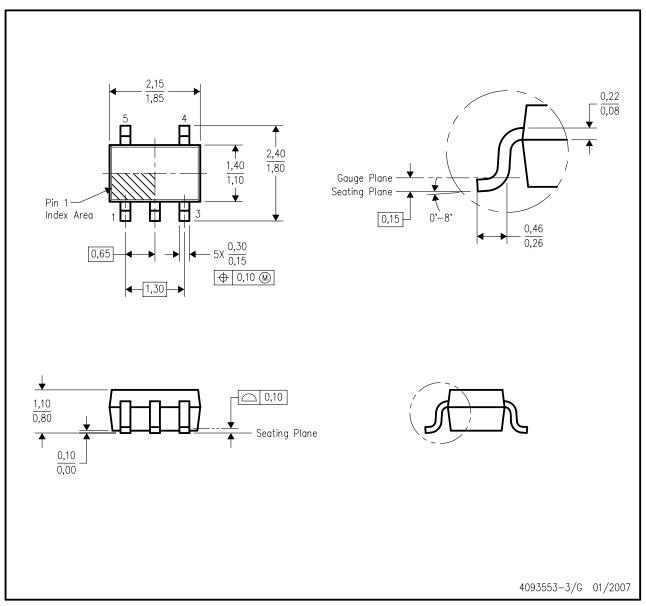
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



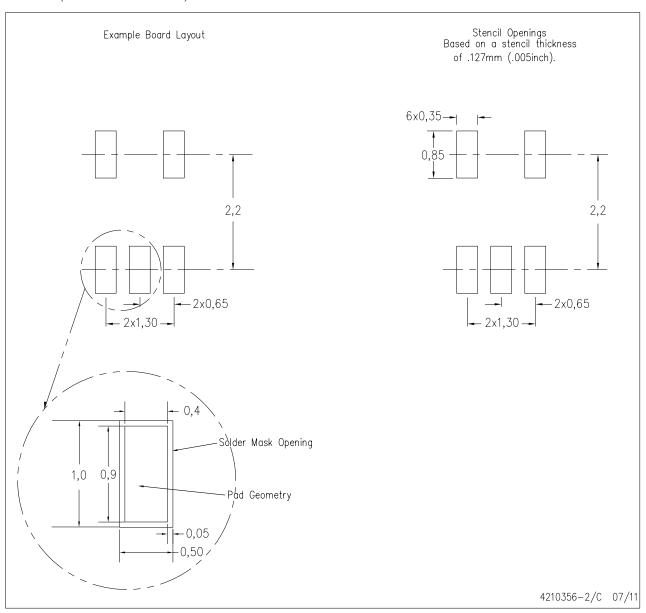
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.





DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



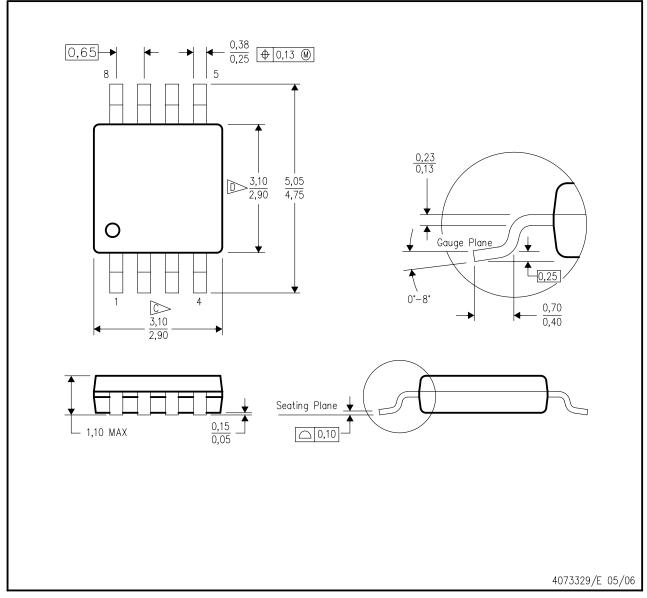
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



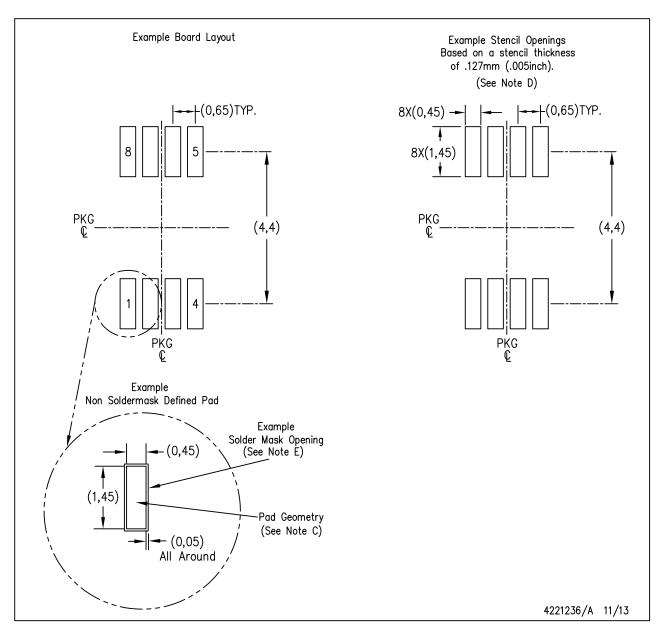
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.





DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



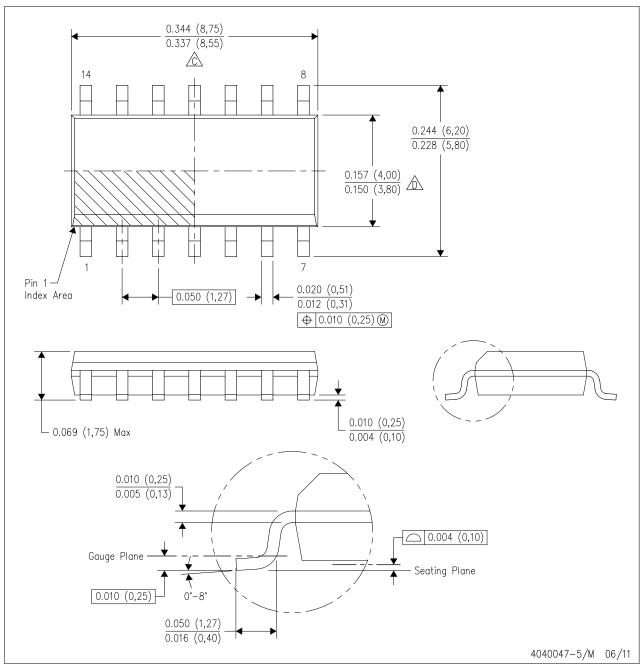
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





D (R-PDS0-G14)

PLASTIC SMALL OUTLINE



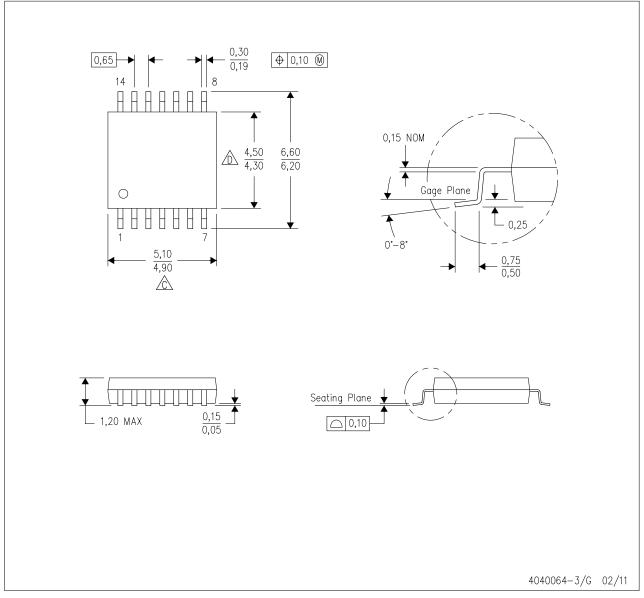
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



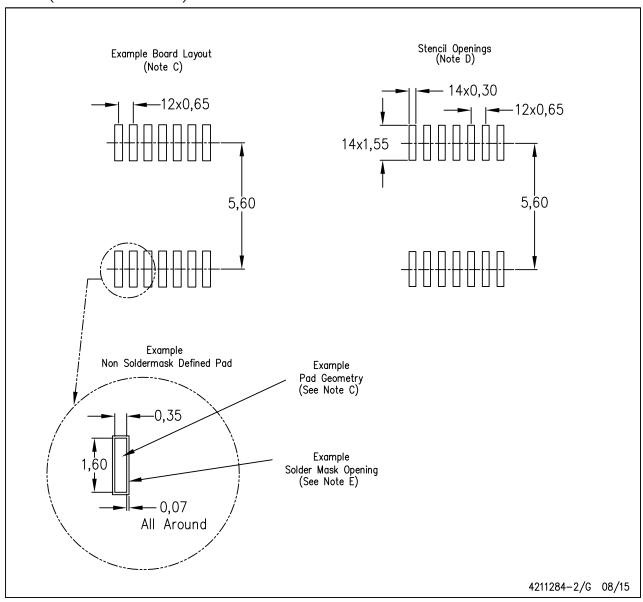
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153





PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



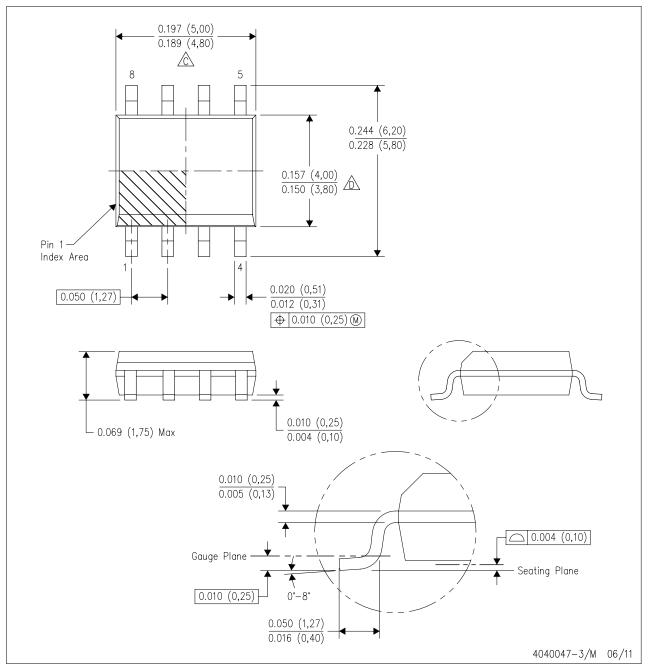
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





Distributor of Texas Instruments: Excellent Integrated System LimitedDatasheet of LMV358Q1MM/NOPB - IC OPAMP GP 1MHZ RRO 8VSSOP

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Amplifiers amplifier.ti.com Communications and Telecom www.ti.com/communications Computers and Peripherals **Data Converters** dataconverter.ti.com www.ti.com/computers **DLP® Products** Consumer Electronics www.ti.com/consumer-apps www.dlp.com DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical

Power Mgmt Space, Avionics and Defense www.ti.com/space-avionics-defense

Security

www.ti.com/security

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

Products

Logic

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>

logic.ti.com

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2015, Texas Instruments Incorporated